## NSN 5961-01-293-6458

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-293-6458 **Inclosure Material:** Glass **Overall Length:** Between 0.160 inches and 0.205 inches **Overall Diameter:** Between 0.080 inches and 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1000.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute and 30.00 amperes forward current, average preset **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: